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Semiconductor devices – Micro-electromechanical devices – Part 21: Test method for Poisson's ratio of thin film MEMS materials (Standards.iten.al)

Dispositifs à semiconducteurs – Dispositifs microélectromécaniques – Partie 21: Méthode d'essai relative au coefficient de Poisson des matériaux MEMS en couche mince 6e07e8e03a3friec-62047-21-2014





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INTERNATIONAL ELECTROTECHNICAL COMMISSION

SEMICONDUCTOR DEVICES – MICRO-ELECTROMECHANICAL DEVICES –

Part 21: Test method for Poisson's ratio of thin film MEMS materials

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International Standard IEC 62047-21 has been prepared by subcommittee 47F: Microelectromechanical systems, of IEC technical committee 47: Semiconductor devices.

The text of this standard is based on the following documents:

FDIS	Report on voting
47F/185/FDIS	47F/189/RVD

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

A list of all parts in the IEC 62047 series, published under the general title *Semiconductor devices* – *Micro-electromechanical devices*, can be found on the IEC website.

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<u>IEC 62047-21:2014</u> https://standards.iteh.ai/catalog/standards/sist/13379be3-3241-4af2-bf7f-6e07e8e03a3f/iec-62047-21-2014

SEMICONDUCTOR DEVICES – MICRO-ELECTROMECHANICAL DEVICES –

Part 21: Test method for Poisson's ratio of thin film MEMS materials

1 Scope

This part of IEC 62047 specifies the determination of Poisson's ratio from the test results obtained by the application of uniaxial and biaxial loads to thin-film micro-electromechanical systems (MEMS) materials with lengths and widths less than 10 mm and thicknesses less than 10 μ m.

2 Normative references

The following documents, in whole or in part, are normatively referenced in this document and are indispensable for its application. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

iTeh STANDARD PREVIEW

IEC 62047-8:2011, Semiconductor devices – Micro-electromechanical devices – Part 8: Strip bending test method for tensile property measurement of thin films

ASTM E 132-04:2010, Standard test method for Poisson's ratio at room temperature https://standards.iteh.ai/catalog/standards/sist/13379be3-3241-4af2-bf7f-

6e07e8e03a3f/iec-62047-21-2014

3 Terms, definitions, symbols and designations

3.1 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

3.1.1 Delegende

Poisson's ratio

v

ratio of transverse strain multiplied by (-1) to the corresponding longitudinal strain resulting from uniformly distributed longitudinal stress below the proportional limit of the material, expressed as $-\varepsilon_t/\varepsilon_t$, where ε_t is transverse strain, and ε_t is longitudinal strain

3.2 Symbols and designations

Symbols and designations of two types of test pieces are presented in Figure 1 and Table 1, respectively.



a) Type 1 test piece for uniaxial tensile machine



b) Type 2 test piece for membrane bulging machine

Figure 1 – Two types of test pieces for the measurement of Poisson's ratio https://standards.iteh.ai/catalog/standards/sist/13379be3-3241-4af2-bf7f-

Symbol	Unit	Designation
l ₁	μm	Gauge length for longitudinal strain measurement
l ₂	μm	Gauge length for transverse strain measurement
Ь	μm	Width of test piece
L	μm	Overall length
R	μm	Filet radius of test piece
^m 1	μm	Length of a rectangular membrane
<i>m</i> ₂	μm	Width of a rectangular membrane
<i>m</i> ₃	μm	Diameter of a circular membrane
h	μm	Thickness of membrane

Table 1 – Symbols and designations of a test piece

4 Test piece

4.1 General

The test piece should be prepared using a fabrication process similar to the actual fabrication of devices. It should have dimensions on the same order as those of the mother device to minimise the effect of size-dependent properties. An example of the fabrication process can be found in IEC 62047-8. The gradient of the internal stress in the direction of thickness should be minimised using an annealing process, but the annealing process should be avoided when Young's modulus and Poisson's ratio of the sample can be affected. Two types of test pieces are utilised in this standard and are described in the following 4.2 and 4.3.

4.2 Shape of the test piece

Two types of test pieces are specified in this standard. Type 1 has a shape similar to a tensile specimen (Figure 1a), whereas type 2 has two membranes (Figure 1b). In type 1, two pairs of gauge markers shall be fashioned to define both longitudinal and transverse strains. By measuring the longitudinal and transverse strains, the Poisson's ratio is calculated by the ratio of $-\varepsilon_t/\varepsilon_l$ specified in 3.1. When a wrinkle forms in the test piece during the tensile test due to compressive strain in the transverse direction, undesirable out-of-plane deformation can lead to an error in the optical measurement, obscuring the optical measurement of transverse strain. In this case, a type 2 test piece should be used instead of a type 1 test piece. In type 2, circular and rectangular membranes are included in the test piece. The maximum deflections of the two membranes are measured simultaneously under a given pressure. The pressure applied to the two membranes should be identical. The out-of-plane deflection due to the applied pressure should be measured using an optical technique or atomic force microscopy (AFM) to minimise the mechanical disturbance of the test piece. For the rectangular membrane, the ratio between the length and width (m_1/m_2) should be larger than 4.

4.3 Measurement of dimensions

To analyse the test results, an accurate measurement of the test-piece dimensions is required because the dimensions are used to extract the mechanical properties of test materials. In the type 1 test piece, the longitudinal and transverse gauge lengths (l_1, l_2) , width (b), and thickness (h) shall be measured with an error of less than ± 5 %. In the type 2 test piece, the width (m_2) of the rectangular membrane, the diameter (m_3) of the circular membrane, and the film thickness (h) shall be measured with an error of less than ± 5 %.

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5 Testing method and test apparatus

IEC 62047-21:2014

5.1 Test principle 5.1 Test prin

With a type 1 test piece, the test is performed by applying a tensile load to the test piece. The longitudinal and transverse strains induced by the tensile load should be uniform over a predefined gauge section in the elastic region of the test piece. The longitudinal and transverse strains should be measured simultaneously, and the time delay between them should be less than 1/100 of the data-sampling period. When there is curling in the test piece, it is difficult to measure the transverse strain. In this case, Poisson's ratio should be measured using a type 2 test piece. With a type 2 test piece, the test is performed by applying air pressure to the test piece. The circular and rectangular membranes should experience the same applied pressure. The deflections of both membranes should be measured simultaneously, and the time delay between them should be less than 1/100 of the data-sampling period.

5.2 Test machine

The test machine for a type 1 test piece is similar to a conventional tensile test machine, except that it is capable of measuring transverse strain. Due to the thinness of the test piece, the longitudinal and transverse strains shall be measured using optical techniques such as laser interferometry or digital image correlation (DIC). The test machine for a type 2 test piece consists of an air compressor, air regulator, pressure sensor, and displacement sensor for measuring out-of-plane deflections.

5.3 Test procedure

5.3.1 Test procedure for type 1 test piece

- a) Fix the test piece using the tensile grip. The longitudinal direction of the test piece shall be aligned with the actuating direction of the test apparatus, and the deviation angle shall be less than 1 degree, as specified in 4.4 of IEC 62047-8:2011.
- b) Verify the strain measurement unit for longitudinal and transverse strains. These strain signals shall be measured simultaneously with the load signal.

c) Apply a tensile load to the test piece at a constant strain rate (or grip-to-grip displacement rate). The strain rate shall range from 0,01 min⁻¹ to 10 min⁻¹ depending on the material system of the test piece and the actual usage condition of the customer.

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- d) Unload the test apparatus when the load sufficiently exceeds the proportional limit.
- e) Draw a graph of the longitudinal and transverse strains with respect to load as described in ASTM E 132-04 and determine Poisson's ratio.

5.3.2 Test procedure for type 2 test piece

- a) Fix the test piece to the grip of the test apparatus. The grip should have inlet and outlet ports for air pressure and a connection port that allows air pressure to be applied to the test piece. The air pressure line in the grip should be designed to deliver identical pressure to both membranes in the test piece.
- b) Apply air pressure to both the circular and rectangular membranes in the test piece and measure the central deflections of both membranes and the applied pressure.
- c) Unload the test apparatus when the pressure exceeds the proportional limit of the test piece or if the membranes rupture.
- d) Analyse the test results and determine Poisson's ratio according to Annex B.

5.4 Test environment

Because the mechanical properties are temperature and humidity sensitive, fluctuations in temperature during the test shall be controlled to be less than \pm 2 °C, and the change in relative humidity (RH) in the testing laboratory shall be controlled to be less than \pm 5 % RH. **TICH STANDARD PREVIE**

Test report 6

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The test report shall contain the following information 4

- a) Reference to this international standards/sist/13379be3-3241-4af2-bf7f-
- b) Test piece identification;
- c) Test piece material;
 - using a single crystal: crystallographic orientation;
 - using a poly-crystal: texture and grain size;
- d) Shape and dimensions of the test piece;
- e) Test piece fabrication method details:
 - deposition method;
 - annealing conditions;
 - fabrication conditions;
- f) Testing system:
 - testing apparatus;
 - load and strain measurement method (or pressure and deflection);
- g) Measured properties and results: Poisson's ratio, longitudinal and transverse strains versus applied load (or pressure) curve.

Annex A

(informative)

Measurement example of Poisson's ratio using type 1 test piece

A.1 Fabrication of the test piece

The test piece for measurement of Poisson's ratio is fabricated by MEMS processes. Similar fabrication processes can be found in Annex B of IEC 62047-8:2011.

A.2 Dimensions of the test piece

The test pieces should be fabricated with a length of 2 mm, a width of 500 μ m, and a filet radius of 5 mm (Figure 1). To analyse the test data, dimensions of the test pieces should be measured accurately. The thickness of the test piece is measured to be 2,8 μ m using a scanning electron microscope. As shown in Figure A.1, longitudinal and transverse strains are measured after the markers for strain measurement are defined.

A.3 Test procedures

Tests are performed using a micro-tensile testing apparatus. After the test piece is fixed on jigs, uni-axial tensile force is applied in the longitudinal direction of the test piece using a piezoelectric actuator. The longitudinal direction coincides with the <110> direction of the test piece made of single-crystal silicon. The strain rate is 5×10^{-4} /s during the test. Longitudinal and transverse strains are measured using DIC with the images acquired from a microscope. Markers for DIC are shown in Figure A-1 marger spacing between the two markers of the longitudinal direction leads to higher/resolution of the strain measurement for a given optical system. In this test, the longitudinal and transverse gauge lengths are 250 µm and 173 µm, which are taken from the field of view of the optical system and maximum displacement of the test piece. Both longitudinal and transverse strains ($\varepsilon_{\rm l}$, $\varepsilon_{\rm t}$) and load (*F*) are acquired simultaneously by a data-acquisition module.





b) Markers for transverse strain



A.4 Test results

From the measured data, a $F-\varepsilon$ curve can be obtained (Figure A.2). After fitting the two curves linearly, the slopes of the two curves are obtained as $d\varepsilon_{l}/dF = 0,00443$ and $d\varepsilon_{t}/dF = -0,00113$. Then, Poisson's ratio is calculated by



 $\upsilon = -\frac{d\varepsilon_t/dF}{d\varepsilon_l/dF} = 0,267. \tag{A.1}$

Figure A.2 – Graphs of load and strain in the longitudinal and transverse directions